Reflective Object Sensor

OPB608A, OPB608B, OPB608C, OPB608R, OPB608V

TT Electronics

Features:

- Phototransistor output
- Unfocused for sensing diffuse surface
- Low cost plastic housing
- Enhanced signal to noise ratio
- Reduced ambient light sensitivity
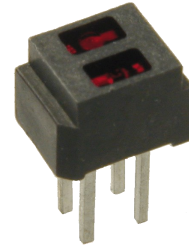
Description:

OPB608 reflective switches consist of an infrared emitting device (LED or VCSEL) and a NPN silicon phototransistor mounted "side-by-side" on a parallel axis in a black opaque plastic housing. All OPB608's **(except OPB608R)** have an emitting device and a phototransistor that are encapsulated in a visible filtering epoxy. The phototransistor responds to radiation from the emitter only when a reflective object passes within its field of view. The phototransistor has enhanced low current roll-off to improve the contrast ratio and immunity to background irradiance. LED versions are designed for near-field applications. The VCSEL version is designed for longer distances.

OPB608A, **OPB608B** and **OPB608C** devices are designed for applications with reflective distances between 0.050" (1.270 mm) and 0.375" (9.525 mm). **OPB608V** is designed for applications with reflective distances between 0.050" (1.270 mm) and 1.200" (30.480 mm). All of these are designed for light patterns not visible to the human eye. By utilizing the night enhancement function of a camera, the near infrared light pattern can be seen. This allows a user to see the pattern shining on the reflective object.

OPB608R is designed for applications with reflective distances between 0.050" (1.270 mm) and 0.300" (7.620 mm). It is designed for light patterns visible to the human eye. The efficiency of this sensor is lower for optical wavelengths in the visible range, thus reducing the distance that can be used.

Reflective distances are dependent upon the drive current for the light emitting device, the wavelength of the light source, and the type of reflective material; therefore, each application should be checked for the ability to meet each requirement.

Custom electrical, wire and cabling and connectors are available. Contact your local representative or OPTEK for more information.

Applications:

- Non-contact reflective object sensor
- Assembly line automation
- Machine automation
- Machine safety
- End of travel sensor
- Door sensor

Ordering Information				
Part Number	LED Peak Wavelength	Sensor	Reflection Distance Inch (mm)	Lead Length
OPB608A	890 nm	Rbe Transistor	See Graph on Page 4	0.18" (Min)
OPB608B				
OPB608C				
OPB608R	650 nm			
OPB608V	850 nm			

Pb
Pb-Free
(RoHS)

**INVISIBLE LASER RADIATION
DO NOT VIEW DIRECTLY WITH
OPTICAL INSTRUMENTS
(MAGNIFIERS)
CLASS 1M LASER PRODUCT
PER IEC/EN 60825-1/A2:2001
0.78mW at 850 nm
Class 1M**

Additional laser safety information can be found on the Optek website. See application #221.

Classification is not marked on the device due to space limitations. See package outline for   centerline of optical radiance. Operating devices beyond maximum rating may cause devices to exceed rated classification

---

Reflective Object Sensor

OPB608A, OPB608B, OPB608C, OPB608R, OPB608V

TT Electronics

Absolute Maximum Ratings (T_A=25°C unless otherwise noted)

Storage Temperature Range		-40° C to +85° C
Operating Temperature Range	OPB608 A, B, C & R OPB608V	-40° C to +85° C 0° C to +70° C
Lead Soldering Temperature [1/16 inch (1.6mm) from the case for 5 sec. with soldering iron][1]		260° C
Total Power Dissipation		100 mW

OPB608A, OPB608B, OPB608C (Infrared-LED — 890 nm)

Forward DC Current	50 mA
Peak Forward Current (1 µs pulse width, 300 pps)	3 A
Reverse DC Voltage	2 V

OPB608R (Visible Red-LED — 650 nm)

Forward DC Current	50 mA
Reverse DC Voltage	5 V

OPB608V (Infrared-VCSEL — 850 nm)

Forward DC Current	12 mA
Reverse DC Voltage	5 V

Phototransistor

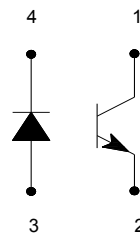|	
Collector-Emitter Voltage	30 V
Emitter Reverse Current	10 mA
Collector DC Current	25 mA

Notes:
(1)   RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
(2)   Methanol or isopropanol are recommended as cleaning agents. The plastic housing is soluble in chlorinated hydrocarbons and keytones.

Pin #	LED	Pin #	Transistor
4	Cathode	1	Collector
3	Anode	2	Emitter
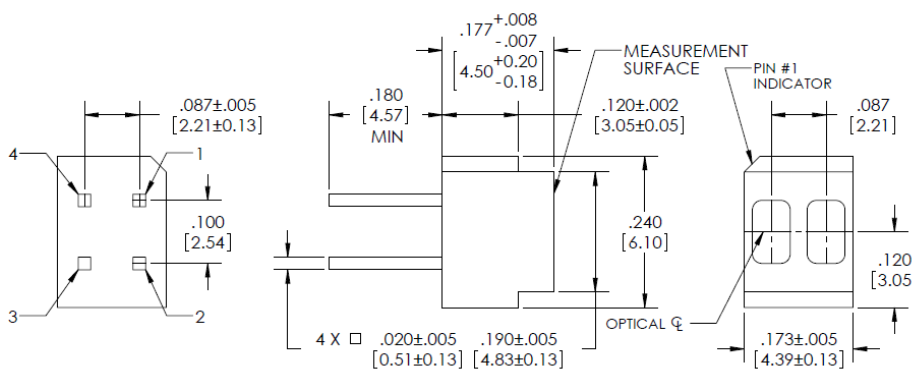
DIMENSIONS ARE IN INCHES AND [MILLIMETERS].
UNLESS OTHERWISE SPECIFIED ALL TOLERANCES ARE ±.005 [±.13]